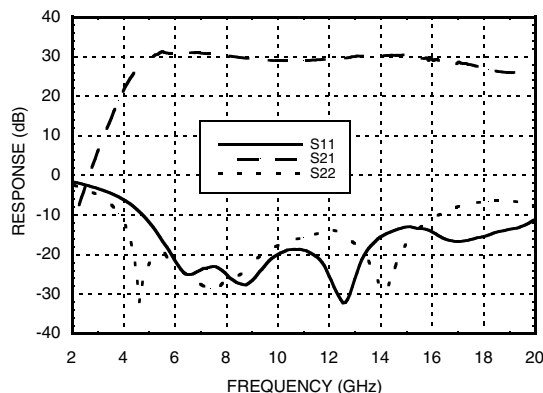
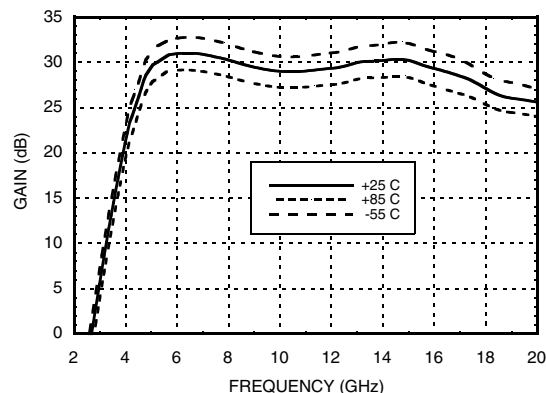
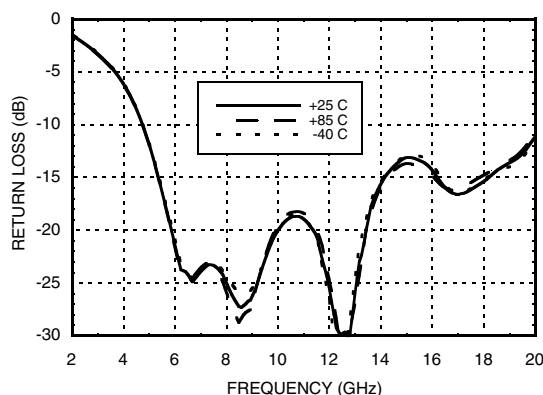
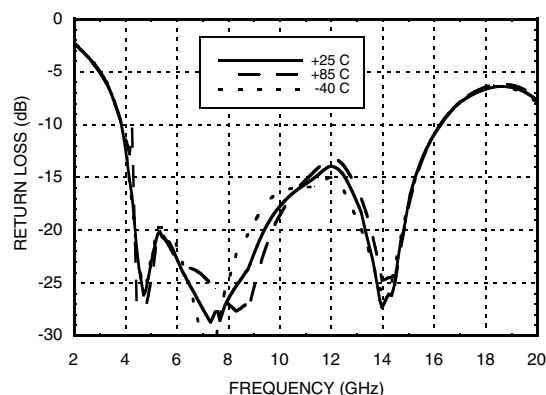
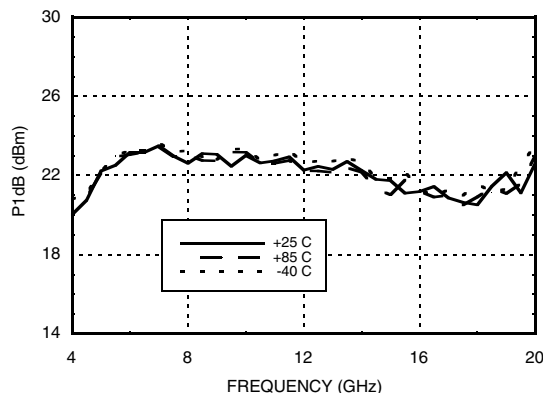
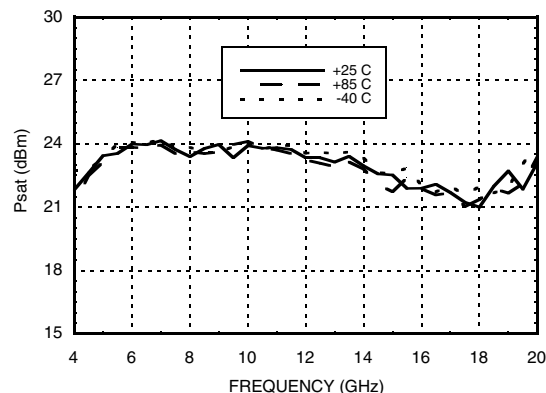
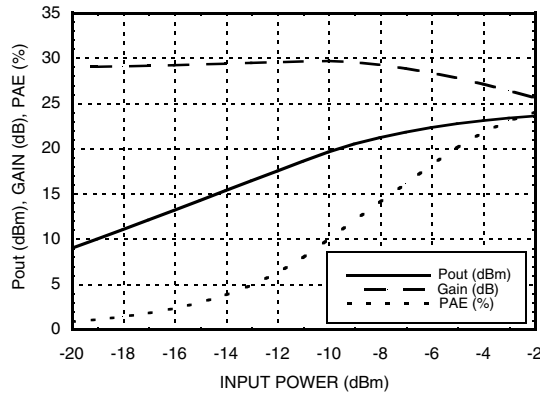



**GaAs PHEMT MMIC DRIVER  
AMPLIFIER, 5.5 - 17 GHz**
**Broadband Gain & Return Loss**

**Gain vs. Temperature**

**Input Return Loss vs. Temperature**

**Output Return Loss vs. Temperature**

**P1dB vs. Temperature**

**Psat vs. Temperature**


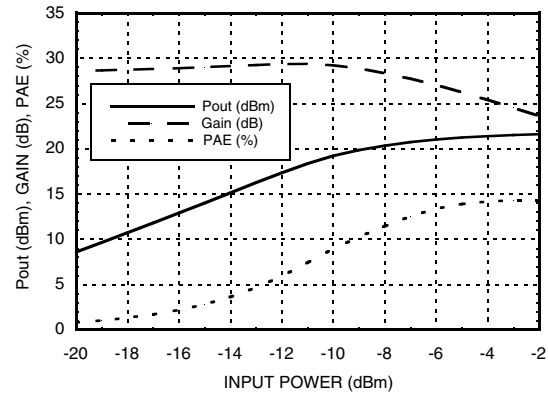


## GaAs PHEMT MMIC DRIVER AMPLIFIER, 5.5 - 17 GHz

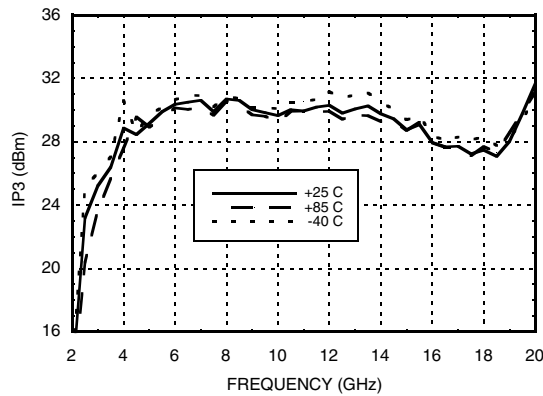
### Power Compression @ 11 GHz



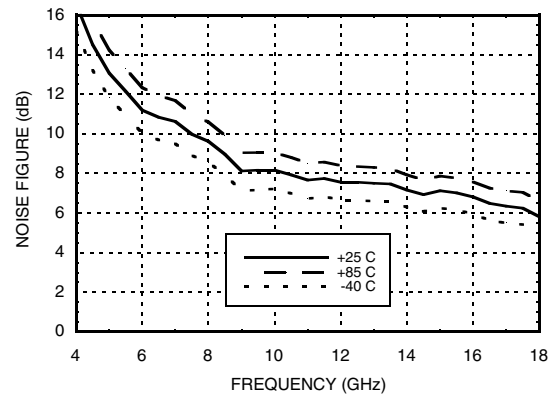
### Power Compression @ 17 GHz



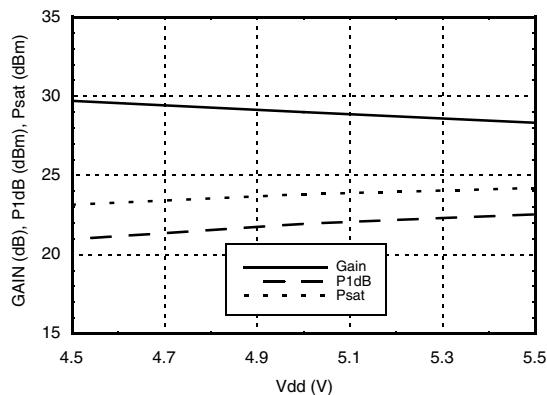
### Output IP3 vs. Temperature



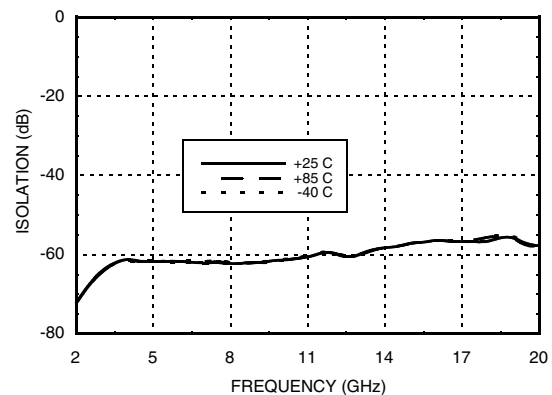
### Noise Figure vs. Temperature



### Gain & Power vs. Supply Voltage @ 11 GHz



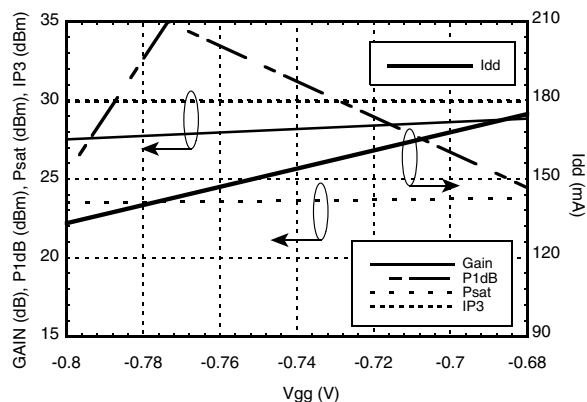
### Reverse Isolation vs. Temperature





## GaAs PHEMT MMIC DRIVER AMPLIFIER, 5.5 - 17 GHz

### Gain, Power & Output IP3 vs. Gate Voltage @ 11 GHz



### Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, Vdd2, Vdd3, Vdd4)	+5.5V
Gate Bias Voltage (Vgg)	-3 to 0V
RF Input Power (RFIN)(Vdd = +5 Vdc)	+5 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 11.08 mW/°C above 85 °C)	0.99 W
Thermal Resistance (channel to package bottom)	90.23 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Typical Supply Current vs. Vdd

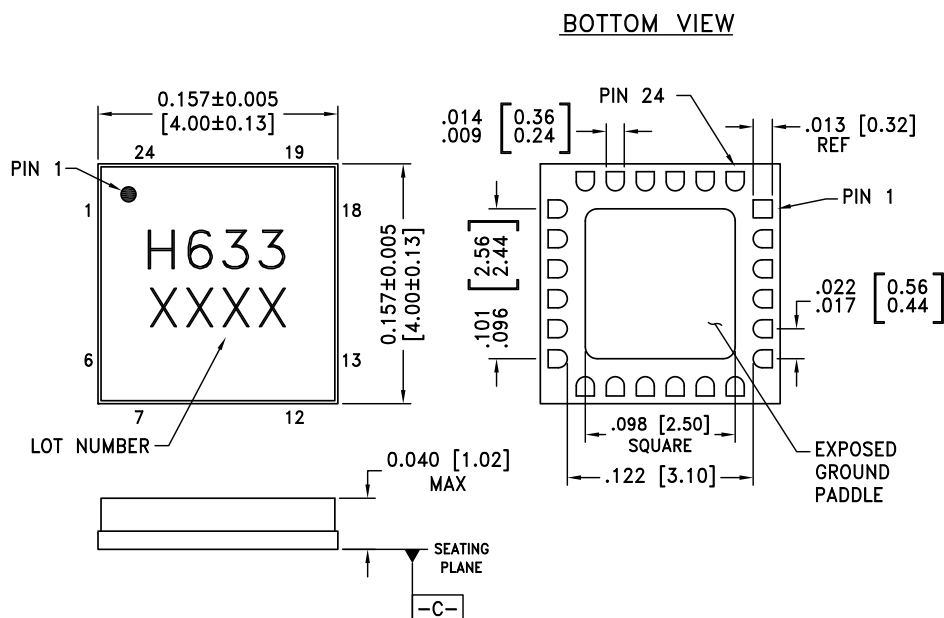
Vdd (V)	Idd (mA)
4.5	177
5.0	180
5.5	182

Note: Amplifier will operate over full voltage ranges shown above



## GaAs PHEMT MMIC DRIVER AMPLIFIER, 5.5 - 17 GHz

## Outline Drawing



NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC633LC4	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H633 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX


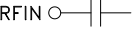
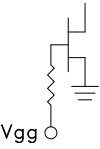
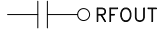
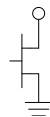
*Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.*

For price, delivery, and to place orders: Analog Devices, Inc.,  
One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106  
Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com)  
Application Support: Phone: 1-800-ANALOG-D



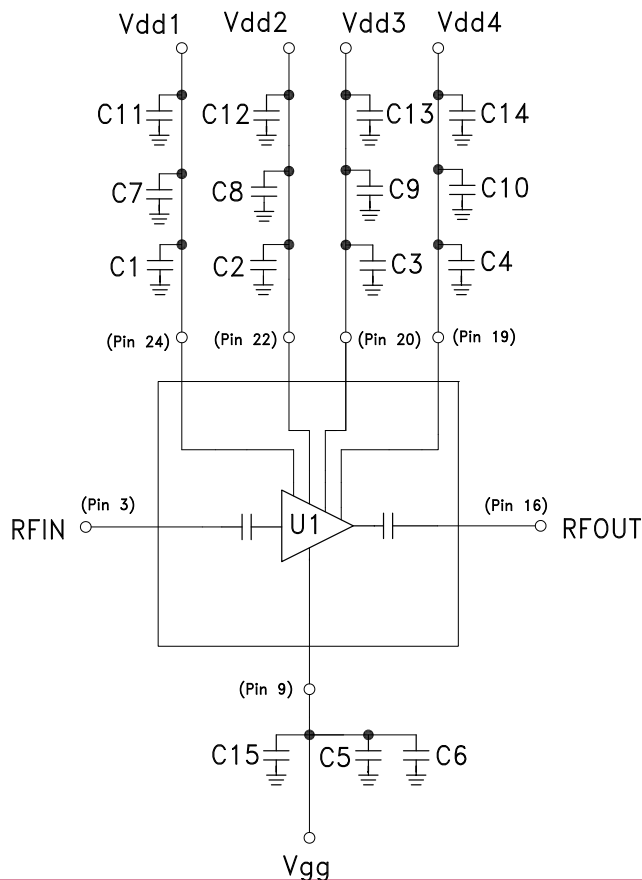
## GaAs PHEMT MMIC DRIVER AMPLIFIER, 5.5 - 17 GHz

### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5 - 8, 11 - 14, 18, 21, 23	N/C	No connection. These pins may be connected to DC/RF ground. Performance will not be affected.	
2, 4, 15, 17	GND	Package Bottom must be connected to RF/DC ground.	
3	RFIN	This pin is AC coupled and matched to 50 Ohms.	
9	Vgg	Gate control for amplifier, please follow "MMIC Amplifier Biasing Procedure" Application Note: See application circuit for required external components.	
16	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
24, 22, 20, 19	Vdd1, Vdd2, Vdd3, Vdd4	Power Supply Voltage for the amplifier. See application circuit for required external components.	

### Application Circuit

Component	Value
C1 - C5	100 pF
C6 - C10	1000 pF
C11 - C15	2.2 $\mu$ F



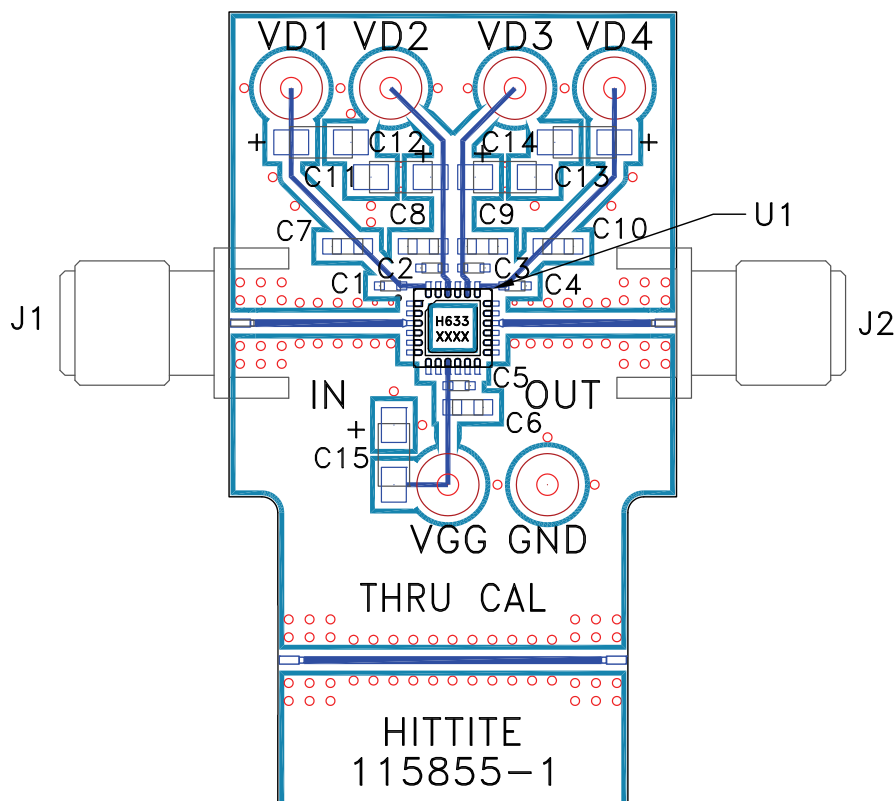
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



**GaAs PHEMT MMIC DRIVER  
AMPLIFIER, 5.5 - 17 GHz**

**Evaluation PCB**



**List of Materials for Evaluation PCB 115857 <sup>[1]</sup>**

Item	Description
J1 - J2	2.92 mm PC Mount K-Connector
VD1 - VD4	DC Pin
C1 - C5	100 pF Capacitor, 0402 Pkg.
C6 - C10	1000 pF Capacitor, 0603 Pkg.
C11 - C15	2.2 $\mu$ F Capacitor, Tantalum
U1	HMC633LC4 Driver Amplifier
PCB <sup>[2]</sup>	115855 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

**GaAs PHEMT MMIC DRIVER  
AMPLIFIER, 5.5 - 17 GHz**